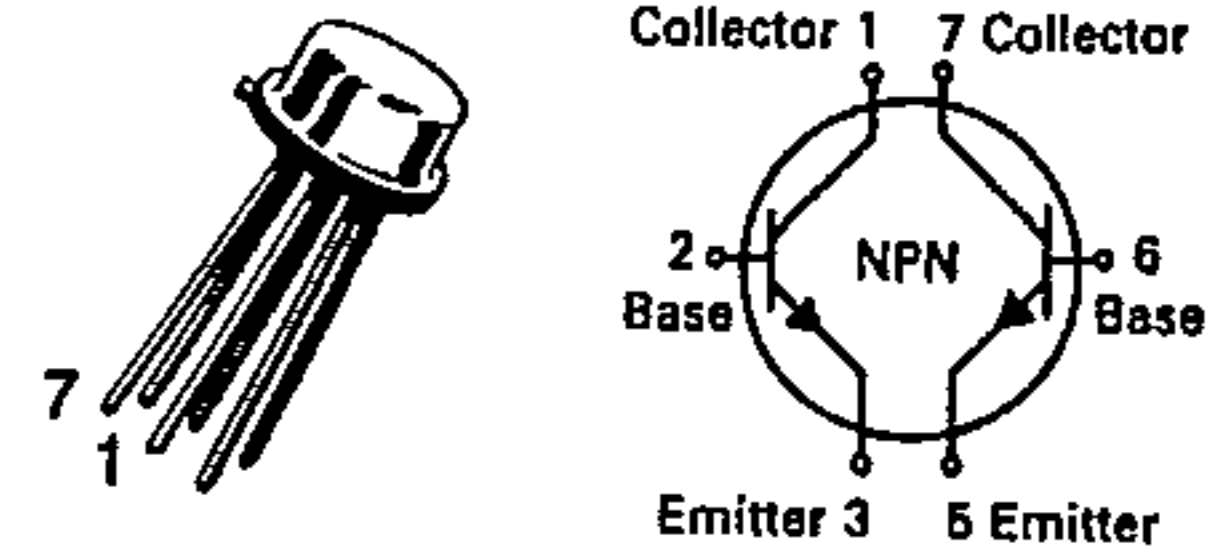


# 2N2639 thru 2N2644

CASE 654-07, STYLE 1



**DUAL  
AMPLIFIER TRANSISTORS**

**NPN SILICON**

Refer to 2N2913 for graphs.

## MAXIMUM RATINGS

Rating	Symbol	Value		Unit
Collector-Emitter Voltage	$V_{CEO}$	45		Vdc
Collector-Base Voltage	$V_{CBO}$	45		Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0		Vdc
Collector Current — Continuous	$I_C$	30		mAdc
		One Die	Both Die	
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 1.72	600 3.43	mW mW/°C
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	600 3.43	1200 6.87	mW mW/°C
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200		°C

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit	
<b>OFF CHARACTERISTICS</b>					
Collector-Emitter Sustaining Voltage(1) ( $I_C = 10 \text{ mAdc}, I_B = 0$ )	$V_{CEO(sus)}$	45	—	Vdc	
Collector Cutoff Current ( $V_{CE} = 5.0 \text{ Vdc}, I_B = 0$ )	$I_{CEO}$	—	0.010	$\mu\text{Adc}$	
Collector Cutoff Current ( $V_{CB} = 45 \text{ Vdc}, I_E = 0$ ) ( $V_{CB} = 45 \text{ Vdc}, I_E = 0, T_A = +150^\circ\text{C}$ )	$I_{CBO}$	— —	0.010 10	$\mu\text{Adc}$	
Emitter Cutoff Current ( $V_{EB} = 5.0 \text{ Vdc}, I_C = 0$ )	$I_{EBO}$	—	0.010	$\mu\text{Adc}$	
<b>ON CHARACTERISTICS(1)</b>					
DC Current Gain ( $I_C = 10 \mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$	2N2639, 2N2640, 2N2641 2N2642, 2N2643, 2N2644	50	300	—
( $I_C = 10 \mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}, T_A = -55^\circ\text{C}$ )			100	300	—
( $I_C = 10 \mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}, T_A = -55^\circ\text{C}$ )			10	—	—
( $I_C = 10 \mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}, T_A = -55^\circ\text{C}$ )			20	—	—
( $I_C = 100 \mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$	2N2639, 2N2640, 2N2641 2N2642, 2N2643, 2N2644	55	—	—
( $I_C = 100 \mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}$ )			110	—	—
( $I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$	2N2639, 2N2640, 2N2641 2N2642, 2N2643, 2N2644	65	—	—
( $I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ )			130	—	—
Collector-Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$ )	$V_{CE(sat)}$	—	1.0	Vdc	
Base-Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$ )	$V_{BE(sat)}$	0.6	1.0	Vdc	
<b>SMALL-SIGNAL CHARACTERISTICS</b>					
Current-Gain — Bandwidth Product ( $I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 20 \text{ MHz}$ )	$f_T$	40	—	MHz	
Output Capacitance ( $V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$ )	$C_{obo}$	—	8.0	pF	
Input Impedance ( $I_C = 1.0 \text{ mAdc}, V_{CB} = 5.0 \text{ Vdc}, f = 1.0 \text{ kHz}, I_E = -1.0 \text{ mA}$ )	$h_{ib}$	25	32	ohms	
Voltage Feedback Ratio ( $I_C = 1.0 \text{ mAdc}, V_{CB} = 5.0 \text{ Vdc}, f = 1.0 \text{ kHz}, I_E = -1.0 \text{ mA}$ )	$h_{rb}$	—	600	$\times 10^{-6}$	

## 2N2639 thru 2N2644

ELECTRICAL CHARACTERISTICS (continued) ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
Small-Signal Current Gain ( $I_C = 1.0 \text{ mA dc}$ , $V_{CB} = 5.0 \text{ V dc}$ , $f = 1.0 \text{ kHz}$ ) 2N2639, 2N2640, 2N2641 2N2642, 2N2643, 2N2644	$h_{fe}$	65 130	600 600	—
Output Admittance ( $I_C = 1.0 \text{ mA dc}$ , $V_{CB} = 5.0 \text{ V dc}$ , $f = 1.0 \text{ kHz}$ , $I_E = -1.0 \text{ mA}$ )	$h_{ob}$	—	1.0	$\mu\text{mhos}$
Noise Figure ( $I_C = 10 \mu\text{A dc}$ , $V_{CB} = 5.0 \text{ V dc}$ , $R_S = 10 \text{ k}\Omega$ , Bandwidth = 10 Hz to 15 kHz)	NF	—	4.0	dB

## MATCHING CHARACTERISTICS

DC Current Gain Ratio(2) ( $I_C = 10 \mu\text{A dc}$ , $V_{CE} = 5.0 \text{ V dc}$ ) 2N2639, 2N2642 2N2640, 2N2643	$h_{FE1}/h_{FE2}$	0.9 0.8	1.0 1.0	—
Base-Emitter Voltage Differential ( $I_C = 10 \mu\text{A dc}$ , $V_{CE} = 5.0 \text{ V dc}$ ) 2N2639, 2N2642 2N2640, 2N2643	$ V_{BE1} - V_{BE2} $	— —	5.0 10	mVdc
Base-Emitter Voltage Differential Gradient ( $I_C = 10 \mu\text{A dc}$ , $V_{CE} = 5.0 \text{ V dc}$ , $T_A = -55$ to $+125^\circ\text{C}$ ) 2N2639, 2N2642 2N2640, 2N2643	$\frac{\Delta(V_{BE1} - V_{BE2})}{\Delta T_A}$	— —	10 20	$\mu\text{V}/^\circ\text{C}$

(1) Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .(2) The lowest  $h_{FE}$  reading is taken as  $h_{FE1}$  for this test.